



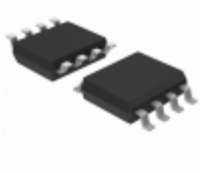




	<h2>SI4390DY-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI4390DY-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 8.5A 8SOIC</p> <p>Datenblätter:  SI4390DY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8910977 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4390DY-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 8.5A 8SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	8910977 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	1.4W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.5A (Ta)
Rds On (Max) @ Id, Vgs	9.5 mOhm @ 12.5A, 10V
VGS (th) (Max) @ Id	2.8V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI4390DY-T1-E3 ist neu im Original, Suche SI4390DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4390DY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4390DY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4390DY VIS SI4390DY VIS</p>	 <p>SI4390DY-T1-E3 Vishay SI4390DY-T1-E3 Vishay</p>	 <p>SI4390DY-T1 VISHAY SI4390DY-T1 VISHAY</p>	 <p>SI4390DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 8.5A 8SOIC</p>
 <p>SI4388DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 10.7A 8-SOIC</p>	 <p>SI4388DY-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 10.7A 8-SOIC</p>	 <p>SI4390DY-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 8.5A 8SOIC</p>	 <p>SI4388DY-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 10.7A 8-SOIC</p>

heiße Teile

Mehr

 SI4364DY-T1-E3	 SI4366DY-T1-E3	 SI4368DY	 SI4368DY-T1-E3	 SI4368DY-T1-E3
 SI4370DY-T1-E3	 SI4376DY-T1-E3	 SI4378DY-T1	 SI4378DY-T1-E3	 SI4378DY-T1-E3
 SI4382DY-T1-E3	 SI4384DY	 SI4384DY-T1-E3	 SI4384DY-T1-E3	 SI4384DY-T1-E3..
 SI4386DY	 SI4386DY-T1-E3	 SI4386DY-T1-E3	 SI4386DY-T1-GE3	 SI4386DY-T1-GE3
 SI4388DY	 SI4388DY-T1-GE3	 SI4388DY-T1-GE3	 SI4390DY	 SI4390DY-T1
 SI4390DY-T1-E3	 SI4390DY-T1-E3	 SI4392ADY	 SI4392ADY-T1-E3	 SI4392DY
 SI4392DY-T1-E3	 SI4392DY-T1-E3.	 SI4392DY-T1-E3..	 SI4394DY	 SI4394DY-T1-E3
 SI4396DY	 SI4396DY-T1-E3	 SI4396DY-T1-E3	 SI4398DY-T1-E3	 SI4398DY-T1-E3
 SI4401BDY-T1-E3	 SI4401BDY-T1-E3	 SI4401BDY-T1-E3.	 SI4401BDY-T1-GE3	 SI4401BDY-T1-GE3
 SI4401DDY	 SI4401DDY-T1-E3	 SI4401DDY-T1-GE3	 SI4401DDY-T1-GE3	 SI4401DY-T1-E3

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